- Ultra-Fast Operation . . . 10 ns (typ)
- Low Positive Supply Current 12.7 mA (Typ)
- Operates From a Single 5-V Supply or From a Split ±5-V Supply
- Complementary Outputs
- Input Common-Mode Voltage Includes Negative Rail
- Low Offset Voltage
- No Minimum Slew Rate Requirement
- Output Latch Capability
- Functional Replacement to the LT1116

### description

The TL3116 is an ultra-fast comparator designed to interface directly to TTL logic while operating from either a single 5-V power supply or dual ±5-V supplies. The input common-mode voltage extends to the negative rail for ground sensing applications. It features extremely tight offset voltage and high gain for precision applications. It has complementary outputs that can be latched using the LATCH ENABLE terminal. Figure 1 shows the positive supply current of the comparator. The TL3116 only requires 12.7 mA (typical) to achieve a propagation delay of 10 ns.

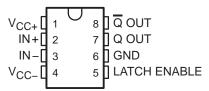
The TL3116 is a pin-for-pin functional replacement for the LT1116 comparator, offering high-speed operation but consuming much less power.

#### **AVAILABLE OPTIONS**

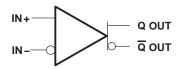
	PACKAGED DEVICES						
TA	SMALL OUTLINE† (D)	TSSOP (PW)	CHIP FORM <sup>‡</sup> (Y)				
0°C to 70°C	TL3116CD	TL3116CPWLE	TL3116Y				
-40°C to 85°C	TL3116ID	TL3116IPWLE	_				

<sup>†</sup>The PW packages are available left-ended taped and reeled only.

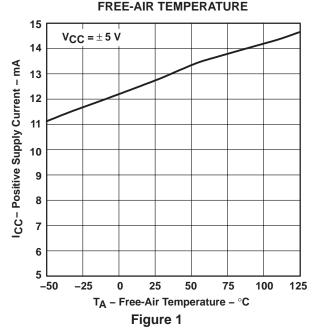
#### D AND PW PACKAGE (TOP VIEW)



### symbol (each comparator)



# POSITIVE SUPPLY CURRENT VS





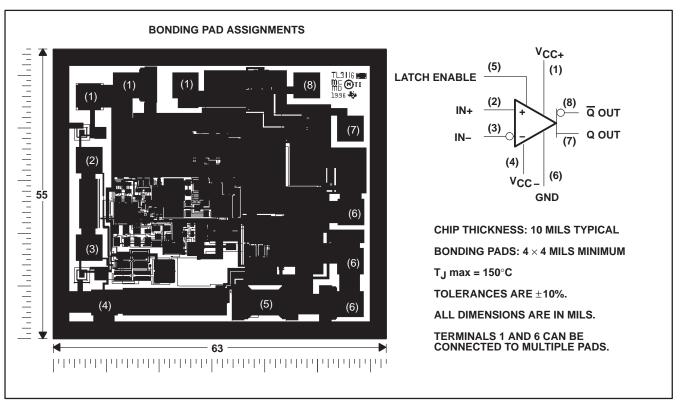
Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.



<sup>‡</sup> Chip forms are tested at  $T_A = 25$ °C only.

### **TL3116Y chip information**

This chip, when properly assembled, displays characteristics similar to the TL3116C. Thermal compression or ultrasonic bonding may be used on the doped-aluminum bonding pads. Chips may be mounted with conductive epoxy or a gold-silicon preform.



COMPONENT COUNT						
Bipolars	53					
MOSFETs	49					
Resistors	46					
Capacitors	14					



### TL3116, TL3116Y ULTRA-FAST LOW-POWER PRECISION COMPARATORS

SLCS132C - MARCH 1997 - REVISED MAY 1997

### absolute maximum ratings over operating free-air temperature range (unless otherwise noted)†

Supply voltage, V <sub>DD</sub> (see Note 1)	
Differential input voltage, V <sub>ID</sub> (see Note 2)	
Input voltage range, V <sub>1</sub>	
Input voltage, V <sub>I</sub> (LATCH ENABLE)	
Output current, I <sub>O</sub>	
Continuous total power dissipation	See Dissipation Rating Table
Operating free-air temperature range, T <sub>A</sub>	–40°C to 85°C
Storage temperature range, T <sub>stq</sub>	– 65°C to 150°C
Lead temperature 1,6 mm (1/16 inch) from case for 10 seconds	

NOTES: 1. All voltage values, except differential voltages, are with respect to network ground.

2. Differential voltages are at IN+ with respect to IN -.

#### **DISSIPATION RATING TABLE**

PACKAGE	T <sub>A</sub> ≤ 25°C POWER RATING	DERATING FACTOR ABOVE T <sub>A</sub> = 25°C	T <sub>A</sub> = 70°C POWER RATING		
D	725 mW	5.8 mW/°C	464 mW		
PW	525 mW	4.2 mW/°C	336 mW		



<sup>†</sup> Stresses beyond those listed under "absolute maximum ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "recommended operating conditions" is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

## TL3116, TL3116Y ULTRA-FAST LOW-POWER PRECISION COMPARATORS

SLCS132C - MARCH 1997 - REVISED MAY 1997

### electrical characteristics at specified operating free-air temperature, $V_{DD}$ = $\pm 5$ V, $V_{LE}$ = 0 (unless otherwise noted)

242445752	TEGT COMPLETIONS.		TL3116C		TL3116I			
PARAMETER	TEST CONDITIONS!	MIN	TYP‡	MAX	MIN	TYP‡	MAX	UNIT
lanut effect veltere	T <sub>A</sub> = 25°C		0.5	3		0.5	3	\/
input offset voltage	T <sub>A</sub> = full range			3.5			3.5	mV
Temperature coefficient of input offset voltage			-2.5			-2.8		μV/°C
	T <sub>A</sub> = 25°C		0.1	0.2		0.1	0.2	
Input offset current	T <sub>A</sub> = full range			0.3			0.35	μΑ
	T <sub>A</sub> = 25°C		0.7	1.1		0.7	1.1	
Input bias current	T <sub>A</sub> = full range			1.2			1.5	μΑ
Common-mode input	V <sub>DD</sub> = ±5 V	-5		2.5	-5		2.5	
voltage range	V <sub>DD</sub> = 5 V	0		2.5	0		2.5	V
Common-mode rejection ratio	-5 ≤ V <sub>IC</sub> ≤ 2.5 V	75	100		75	100		dB
Supply-voltage rejection	Positive supply: 4.6 V $\leq$ +V <sub>DD</sub> $\leq$ 5.4 V, T <sub>A</sub> = 25°C		80		60	80		
ratio	Negative supply: $-7 \text{ V} \le -\text{V}_{DD} \le -2 \text{ V}$ , $T_A = 25^{\circ}\text{C}$	80	100		80	100		dB
Landard advisor	$I_{(sink)} = 4 \text{ mA}, V+ \leq 4.6 \text{ V},$ $T_A = 25^{\circ}\text{C}$		400	600		400	600	
Low-level output voltage	$I_{(sink)}$ = 10 mA, V+ $\leq$ 4.6 V, $T_A$ = 25°C		750			750		mV
I Park I south out out on the con-	$V+ \leq 4.6 \text{ V}, \\ T_A = 25^{\circ}\text{C}$ $I_O = 1 \text{ mA},$	3.6	3.9		3.6	3.9		.,
High-level output voltage	$V+ \leq 4.6 \ V, \\ T_{\mbox{\scriptsize A}} = 25 \mbox{\rm °C} \label{eq:total one of the constraint}$	3.4	3.8		3.4	3.8		V
Positive supply current	T. Gilliana and		12.7	14.7		12.7	15	4
Negative supply current	I <sub>A</sub> = full range	-2.6			-3			mA
Low-level input voltage (LATCH ENABLE)				0.8			0.8	٧
High-level input voltage (LATCH ENABLE)		2			2			V
Low-level input current	V <sub>LE</sub> = 0		0	1		0	1	μΑ
(LATCH ENABLE)	V <sub>LE</sub> = 2 V		24	39		24	45	μΑ
	of input offset voltage  Input offset current  Input bias current  Common-mode input voltage range  Common-mode rejection ratio  Supply-voltage rejection ratio  Low-level output voltage  Positive supply current  Negative supply current  Low-level input voltage (LATCH ENABLE)  High-level input current	$ \begin{array}{c} \text{Input offset voltage} & \begin{array}{c} T_{A} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \end{array} \\ \hline \text{Temperature coefficient of input offset voltage} \\ \hline \text{Input offset current} & \begin{array}{c} T_{A} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \end{array} \\ \hline \text{Input offset current} & \begin{array}{c} T_{A} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \end{array} \\ \hline \text{Input bias current} & \begin{array}{c} T_{A} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \end{array} \\ \hline \text{Common-mode input voltage range} & \begin{array}{c} V_{DD} = \pm 5 \text{ V} \\ V_{DD} = 5 \text{ V} \end{array} \\ \hline \text{Common-mode rejection ratio} & \begin{array}{c} -5 \leq \text{V}_{ C} \leq 2.5 \text{ V} \end{array} \\ \hline \text{Supply-voltage rejection ratio} & \begin{array}{c} P_{\text{Ositive supply: } 4.6 \text{ V} \leq +\text{V}_{DD} \leq 5.4 \text{ V},} \\ T_{A} = 25^{\circ}\text{C} \\ \hline \text{Negative supply: } -7 \text{ V} \leq -\text{V}_{DD} \leq -2 \text{ V},} \\ T_{A} = 25^{\circ}\text{C} \\ \hline \text{I(sink) = 10 mA,} & \text{V+} \leq 4.6 \text{ V},} \\ T_{A} = 25^{\circ}\text{C} \\ \hline \text{I(sink) = 10 mA,} & \text{V+} \leq 4.6 \text{ V},} \\ T_{A} = 25^{\circ}\text{C} \\ \hline \end{array} \\ \hline \text{Positive supply current} \\ \hline \text{Negative supply current} \\ \hline \text{Negative supply current} \\ \hline \text{Low-level input voltage} \\ \hline \text{I(ATCH ENABLE)} \\ \hline \text{Low-level input current} \\ \hline \text{Low-level input current} \\ \hline \text{Low-level input current} \\ \hline \end{array} \\ \hline \text{VLE = 0} \\ \hline \end{array}$	$ \begin{array}{c} \text{Input offset voltage} \\ \text{Ta} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \\ \\ \text{Input offset current} \\ \\ \text{Input offset current} \\ \\ \text{Input offset current} \\ \\ \text{Input bias current} \\ \\ \text{Input bias current} \\ \\ \text{Input bias current} \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \hline T_{A} = \text{full range} \\ \\ \text{Common-mode input voltage range} \\ \\ \text{Common-mode rejection ratio} \\ \\ \text{Common-mode rejection ratio} \\ \\ \text{Supply-voltage rejection ratio} \\ \\ \text{Supply-voltage rejection ratio} \\ \\ \text{Dositive supply: } -5 \leq V_{IC} \leq 2.5 \text{ V} \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{Negative supply: } -7 \text{ V} \leq -V_{DD} \leq -2 \text{ V}, \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{I(sink)} = 4 \text{ mA}, \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{I(sink)} = 10 \text{ mA}, \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V+} \leq 4.6 \text{ V}, \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V+} \leq 4.6 \text{ V}, \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V+} \leq 4.6 \text{ V}, \\ \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V} \leq 4.6 \text{ V}, \\ \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V} \leq 4.6 \text{ V}, \\ \\ \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V} \leq 4.6 \text{ V}, \\ \\ \\ \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V} \leq 4.6 \text{ V}, \\ \\ \\ \\ \\ \\ \\ \\ \\ \text{Ta} = 25^{\circ}\text{C} \\ \\ \text{V} \leq 4.6 \text{ V}, \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\ \\$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{c ccccccccccccccccccccccccccccccccccc$	$ \begin{array}{ c c c c c c c c c c c c c c c c c c c$

<sup>†</sup> Full range for the TL3116C is  $T_A = 0^{\circ}$ C to  $70^{\circ}$ C. Full range for the TL3116I is  $T_A = -40^{\circ}$ C to  $85^{\circ}$ C. ‡ All typical values are measures with  $T_A = 25^{\circ}$ C.

### switching characteristics, $V_{DD} = \pm 5 \text{ V}$ , $V_{LE} = 0$

DADAMETED		TEST 601	TL3116C			TL3116I			LINUT	
	PARAMETER	TEST CONDITIONS†		MIN	TYP	MAX	MIN	TYP	MAX	UNIT
	$\Delta V_{\parallel} = 100 \text{ mV},$	T <sub>A</sub> = 25°C		9.9	12		9.9	12		
	$V_{OD} = 5 \text{ mV}$	T <sub>A</sub> = full range		9.9	14		9.9	15		
<sup>t</sup> pd1	Propagation delay time‡	$\Delta V_{I} = 100 \text{ mV},$	T <sub>A</sub> = 25°C		8.2	10.3		8.2	10.3	ns
		$V_{OD} = 20 \text{ mV}$	T <sub>A</sub> = full range		8.2	12.7		8.2	13.7	
t <sub>sk(p)</sub>	Pulse skew ( $ t_{pd+} - t_{pd-} $ )	$\Delta V_I = 100 \text{ mV},$ $T_A = 25^{\circ}\text{C}$	$V_{OD} = 5 \text{ mV},$		0.5			0.5		ns
t <sub>su</sub>	Setup time, LATCH ENABLE				3.4			3.4		ns

<sup>&</sup>lt;sup>†</sup> Full range for the TL3116C is 0°C to 70°C. Full range for the TL3116I is –40°C to 85°C.

### **TYPICAL CHARACTERISTICS**

### **Table of Graphs**

			FIGURE
		vs Input voltage	2
ICC	Positive supply current	vs Frequency	3
		vs Free-air temperature	4
ICC	Negative supply current	vs Free-air temperature	5
		vs Overdrive voltage	6
	Propagation delay time	vs Supply voltage	7
tpd		vs Input impedance	8
l <sup>*</sup>		vs Load capacitance	9
		vs Free-air temperature	10
V <sub>IC</sub>	Common-mode input voltage	vs Free-air temperature	11
$\vee_{IT}$	Input threshold voltage (LATCH ENABLE)	vs Free-air temperature	12
.,	0	vs Output source current	13
VO	Output voltage	vs Output sink current	14
II	Input current (LATCH ENABLE)	vs Input voltage	15

<sup>‡</sup> t<sub>pd1</sub> cannot be measured in automatic handling equipment with low values of overdrive. The TL3116 is 100% tested with a 1-V step and 500-mV overdrive at T<sub>A</sub> = 25°C only. Correlation tests have shown that t<sub>pd1</sub> limits given can be ensured with this test, if additional dc tests are performed to ensure that all internal bias conditions are correct. For low overdrive conditions, V<sub>OS</sub> is added to the overdrive.

20

18

16

14

12

10

8

2

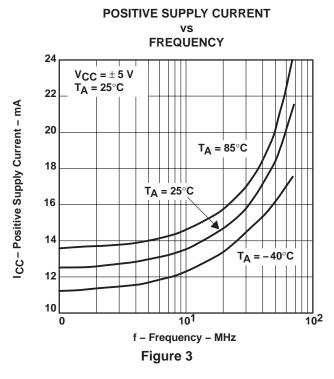
0

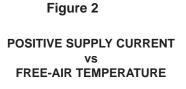
ICC - Positive Supply Current - mA

### TYPICAL CHARACTERISTICS

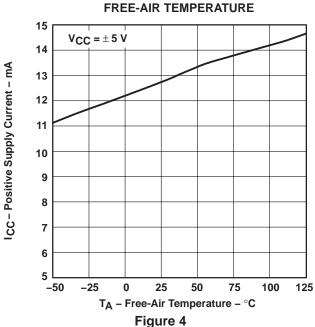
8

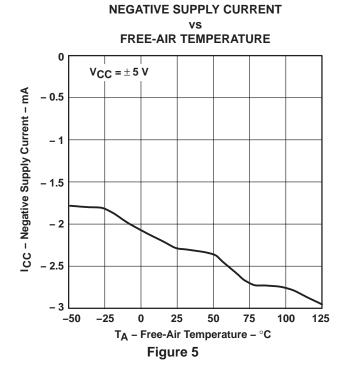
# **POSITIVE SUPPLY CURRENT INPUT VOLTAGE** $V_{CC} = \pm 5 V$ T<sub>A</sub> = 25°C T<sub>A</sub> = 85°C T<sub>A</sub> = 25°C $T_A = -40^{\circ}C$





V<sub>I</sub> - Input Voltage - V





### **TYPICAL CHARACTERISTICS**

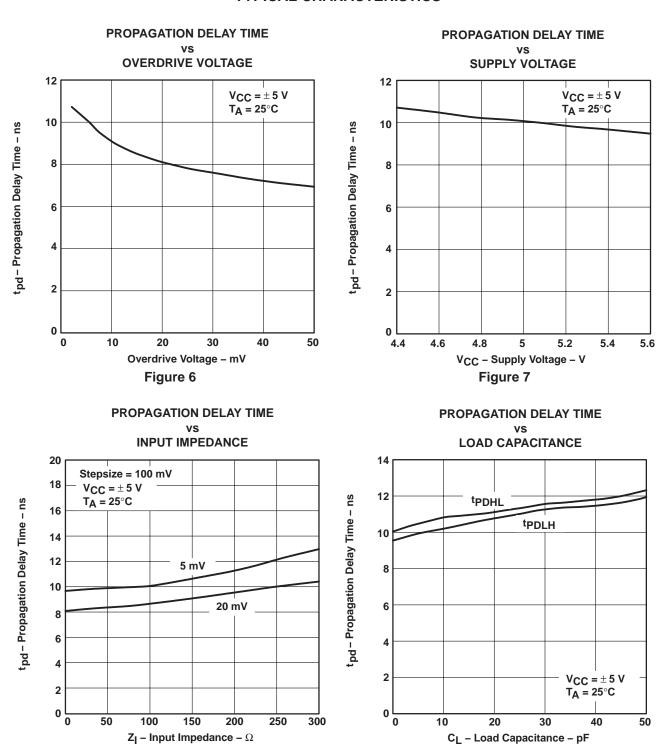


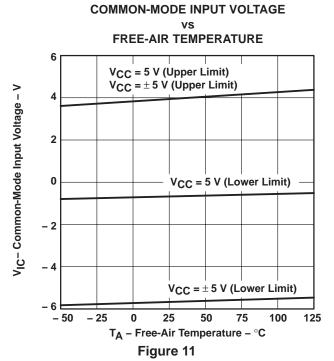


Figure 9

Figure 8

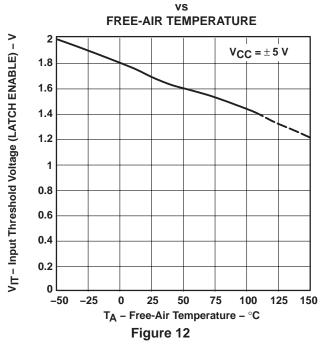
### TYPICAL CHARACTERISTICS

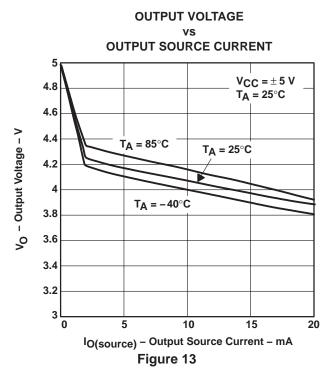
### **PROPAGATION DELAY TIME** FREE-AIR TEMPERATURE 25 $V_{CC} = \pm 5 V$ tpd - Propagation Delay Time - ns 20 15 Rising Edge 10 **Falling Edge** 5 75 100 125 - 50 - 25 50 T<sub>A</sub> - Free-Air Temperature - °C



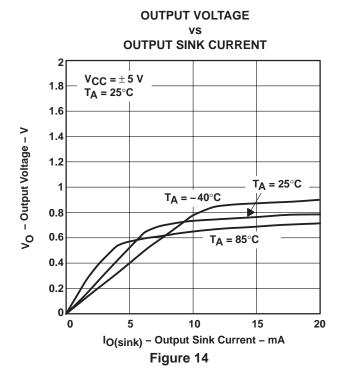
### INPUT THRESHOLD VOLTAGE (LATCH ENABLE)

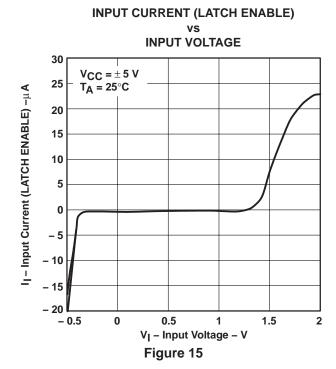
Figure 10





### **TYPICAL CHARACTERISTICS**











### **PACKAGING INFORMATION**

Orderable	Device	Status <sup>(1)</sup>	Package Type	Package Drawing	Pins	Package Qty	e Eco Plan <sup>(2)</sup>	Lead/Ball Finish	MSL Peak Temp (3)
TL3116	CD	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116C	DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL31160	CDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116CI	DRG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL31160	PW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116CF	PWG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116CF	PWLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI
TL3116C	PWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116CP	WRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116	SID	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116II	DG4	ACTIVE	SOIC	D	8	75	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116	IDR	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116ID	RG4	ACTIVE	SOIC	D	8	2500	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116I	PW	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116IP	WG4	ACTIVE	TSSOP	PW	8	150	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116IP	WLE	OBSOLETE	TSSOP	PW	8		TBD	Call TI	Call TI
TL3116IF	PWR	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM
TL3116IP\	VRG4	ACTIVE	TSSOP	PW	8	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-1-260C-UNLIM

<sup>&</sup>lt;sup>(1)</sup> The marketing status values are defined as follows:

**ACTIVE:** Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

**NRND:** Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

**OBSOLETE:** TI has discontinued the production of the device.

**TBD:** The Pb-Free/Green conversion plan has not been defined.

**Pb-Free** (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

**Pb-Free (RoHS Exempt):** This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

<sup>(2)</sup> Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.



### PACKAGE OPTION ADDENDUM

6-Dec-2006

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

### PACKAGE MATERIALS INFORMATION

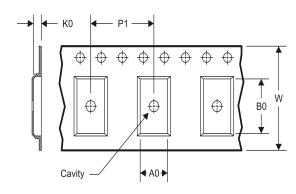
www.ti.com 14-Jul-2012

### TAPE AND REEL INFORMATION

### **REEL DIMENSIONS**



### **TAPE DIMENSIONS**



A0	Dimension designed to accommodate the component width
В0	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

### TAPE AND REEL INFORMATION

\*All dimensions are nominal

Device		Package Drawing		SPQ	Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
TL3116CDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL3116CPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1
TL3116IDR	SOIC	D	8	2500	330.0	12.4	6.4	5.2	2.1	8.0	12.0	Q1
TL3116IPWR	TSSOP	PW	8	2000	330.0	12.4	7.0	3.6	1.6	8.0	12.0	Q1

www.ti.com 14-Jul-2012



\*All dimensions are nominal

7 til diritoriororio dio mominar							
Device	Package Type	Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)
TL3116CDR	SOIC	D	8	2500	367.0	367.0	35.0
TL3116CPWR	TSSOP	PW	8	2000	367.0	367.0	35.0
TL3116IDR	SOIC	D	8	2500	367.0	367.0	35.0
TL3116IPWR	TSSOP	PW	8	2000	367.0	367.0	35.0

### D (R-PDSO-G8)

### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in inches (millimeters).
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0.006 (0,15) each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0.017 (0,43) each side.
- E. Reference JEDEC MS-012 variation AA.



## D (R-PDSO-G8)

### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Publication IPC-7351 is recommended for alternate designs.
- D. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Refer to IPC-7525 for other stencil recommendations.
- E. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



PW (R-PDSO-G8)

### PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters. Dimensioning and tolerancing per ASME Y14.5M—1994.
- B. This drawing is subject to change without notice.
- Body length does not include mold flash, protrusions, or gate burrs. Mold flash, protrusions, or gate burrs shall not exceed 0,15 each side.
- Body width does not include interlead flash. Interlead flash shall not exceed 0,25 each side.
- E. Falls within JEDEC MO-153



#### IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components which meet ISO/TS16949 requirements, mainly for automotive use. Components which have not been so designated are neither designed nor intended for automotive use; and TI will not be responsible for any failure of such components to meet such requirements.

#### Products Applications

Audio Automotive and Transportation www.ti.com/automotive www.ti.com/audio **Amplifiers** amplifier.ti.com Communications and Telecom www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers DI P® Products Consumer Electronics www.dlp.com www.ti.com/consumer-apps

DSP dsp.ti.com **Energy and Lighting** www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface Medical www.ti.com/medical interface.ti.com Logic logic.ti.com Security www.ti.com/security

Power Mgmt <u>power.ti.com</u> Space, Avionics and Defense <u>www.ti.com/space-avionics-defense</u>

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors www.ti.com/omap TI E2E Community e2e.ti.com

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>